Designing heterostructures with higher-temperature superconductivity

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We propose to increase the superconducting transition temperature $T_c$ of strongly correlated materials by designing heterostructures which exhibit a high pairing energy as a result of magnetic fluctuations. More precisely, applying an effective theory of the doped Mott insulator, we envisage a bilayer Hubbard system where both layers exhibit intrinsic intralayer (intraband) $d$-wave superconducting correlations. Introducing a finite asymmetry between the hole densities of the two layers such that one layer becomes slightly more underdoped and the other more overdoped, we show a visible enhancement of $T_c$ compared to the optimally doped isolated layer. Using the bonding and antibonding band basis, we show that the mechanism behind this enhancement of $T_c$ is the interband pairing correlation mediated by the hole asymmetry which strives to decrease the paramagnetic nodal contribution to the superfluid stiffness. For two identical layers, $T_c$ remains comparable to that of the isolated layer until moderate values of the interlayer single-particle tunneling term. These heterostructures shed new light on fundamental questions related to superconductivity.

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I. INTRODUCTION

Since the discovery of high-temperature superconductivity,1 considerable efforts have been devoted to finding out how and why it works.2–11 This puzzling phenomenon—electrical conduction without resistance at temperatures of up to $\sim 130$ K—occurs in complex “copper-oxide” materials (cuprates). After 1987, the term high-$T_c$ superconductor was used interchangeably with cuprate superconductors until iron-based superconductors were discovered.12,13

The Hubbard model is a well-known model of interacting particles in a lattice, with only two terms in the Hamiltonian: a kinetic term allowing for tunneling (“hopping”) of particles between sites of the lattice and a potential term consisting of the exclusion principle. It is relevant to observe that copper-oxide materials are formed interchangeably with cuprate superconductors until iron-based superconductors were discovered.12,13

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Upon doping with holes the antiferromagnetism becomes rapidly destroyed and above a certain level superconductivity occurs with $d_{x^2−y^2}$ pairing symmetry. The $d_{x^2−y^2}$ wave nature of the order parameter has been conclusively shown using phase-sensitive experiments,17–19 for example. The earliest experimental observation for $d$-wave symmetry is based on the linear decrease of the superfluid stiffness with temperature.20

An anisotropic gap with a $d$-wave order parameter has also been observed through photoemission studies.21,22 One scenario to explain the $d_{x^2−y^2}$ wave nature of the superconducting gap relies on spin fluctuations at the wave vector $(\pi,\pi)$ which makes the singlet channel attractive at large momentum transfer. This essentially stems from band-structure nesting effects in two dimensions close to half-filling.23 A similar pairing occurs in ladder systems as a result of short-range valence bond correlations.24,25 In 1986 it was also suggested that backscattering from spin fluctuations might lead to the pairing seen in the Bechgaard salts.26 The same year, three papers argued that spin fluctuations are responsible for $d$-wave pairing in heavy-fermion systems.27–29

How the electronic structure evolves with doping from a Mott insulator into a $d$-wave superconductor is a key issue in understanding the cuprate phase diagram. Over the years it has become clear that states in different parts of momentum space exhibit quite different doping dependencies. The Fermi arcs30–31 or pockets32,33 (near nodal states) retain their coherence as doping is reduced, while the antinodal (near the edge of the first Brillouin zone) states diminish in coherence, becoming completely incoherent at strong underdoping. The antinodes open a gap, “the pseudogap,” which appears well above the superconducting state. It is important to note that the relationship between the pseudogap and superconductivity is still an open subject34,35 even though some efforts have been accomplished from the theoretical and numerical fronts.11,36–45

There are theoretical indications that the high $T_c$ in the cuprates may result from the large magnetic exchange $J$.46–48 Designing a material that can increase $T_c$ certainly requires a better understanding of the mechanisms that reduce the superfluid stiffness with temperature and with the proximity to the Mott insulating state. A number of recent theoretical49–51 and experimental52,53 proposals have explored the possible benefit of combining quite metallic layers with layers of underdoped cuprate materials in heterostructured geometries.

In this paper, we propose to increase $T_c$ using two strongly correlated Hubbard layers, one layer being slightly

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underdoped and the other rather overdoped; here, both layers are characterized by prominent intrinsic d-wave correlations. Using an effective theory of the doped Mott insulator\(^{47,48}\) for both layers, we report an enhancement of the superconducting transition temperature compared to the optimally doped single layer. Another possibility to increase\(T_c\) relies on the presence of a very overdoped “free electron” like layer\(^{59}\) (see Fig. 6).

More precisely, using the bonding and antibonding band representation in the vicinity of optimal doping, we show that the low-energy BCS Hamiltonian exhibits dominant intraband d-wave pairing. Then, we justify how\(T_c\) can be enhanced as a result of (interband) additional superconducting fluctuations mediated by the hole asymmetry between the layers. Our results presented in Fig. 1 indeed reveal an enhancement of\(T_c\) by \(\sim 20\%\) for a slightly underdoped layer with hole density \(\sim 0.15\) and an overdoped layer with hole density \(\sim 0.25\)—these include the possible charge redistribution when coupling the layers; optimal doping here refers to hole densities \(\sim 0.17\). Our findings may have applications to multilayer materials as well as heterostructures. The analysis performed in this paper uses a purely homogeneous model which does not include stripe or density wave structures.\(^{53}\) Other Hubbard bilayer systems have been studied in different parametric regimes.\(^{54,55}\) It is also worth mentioning that correlated bilayers exhibiting either heavy fermions,\(^{56-58}\) composite fermions,\(^{59}\) or exciton condensates\(^{60}\) are also attractive subjects. The realization of high-\(T_c\) superconductivity confined to nanometer-sized interfaces has been a long-standing goal because of potential applications.\(^{61}\)

The outline of the paper is organized as follows. In Sec. II, we introduce the low-energy theory of the bilayer system including the effect of Mott physics (large interactions) and we discuss the general methodology. In Sec. III, we address the situation of symmetric layers and show that there is no enhancement of\(T_c\); nevertheless, we would like to emphasize that the d-wave superconducting state is quite robust toward the proliferation of quasiparticles favored by the single-(quasi)particle tunneling term between the layers and therefore\(T_c\) remains almost constant until moderate values of the interlayer tunneling coupling. We also build the BCS Hamiltonian in the band representation of the bilayer system; this is particularly useful to treat the interlayer hopping nonperturbatively. In Sec. IV, we thoroughly compute the superfluid stiffness and\(T_c\) in the presence of a finite hole asymmetry.

### II. MODEL AND METHODOLOGY

Our starting point is the renormalized low-energy theory\(^{47,62}\) which takes into account the proximity of the Mott insulating ground state. Essentially, the Gutzwiller projector\(^{63}\) ensuring that configurations with doubly occupied sites are forbidden by statistical weighting factors. The projection operator then is eliminated in favor of the reduction factor \(g_{\delta \iota} = 2\delta_i/(1 + \delta_i)\) in the kinetic term\(^{64}\) where \(\delta_i\) represents the hole doping or the number of holes per site in the layer \(\iota = 1\) or 2. In addition, the projection operator enhances spin-spin correlations in each layer: \(g_{\delta i} = 4/(1 + \delta_i)^2\).\(^{47}\)

The bilayer system in the strong-interaction limit then is described by the general Hamiltonian:

\[
H = -gt_1 \sum_{\langle i,j \rangle} c_{i\sigma}^\dagger c_{j\sigma} - t' g_{t1} \sum_{\langle mn \rangle} c_{m\sigma}^\dagger c_{n\sigma} + \text{H.c.}
- gt_2 \sum_{\langle i,j \rangle} d_{i\sigma}^\dagger d_{j\sigma} - t' g_{t2} \sum_{\langle mn \rangle} d_{m\sigma}^\dagger d_{n\sigma} + \text{H.c.}
- t_{g1} g_{\delta 1} \sum_{i\sigma} d_{i\sigma}^\dagger c_{i\sigma} + \text{H.c.}
- \mu_1 \sum_{i\sigma} c_{i\sigma}^\dagger c_{i\sigma} - \mu_2 \sum_{i\sigma} d_{i\sigma}^\dagger d_{i\sigma}
+ J g_{t1} \sum_{\langle i,j \rangle} \mathbf{S}_i^t \cdot \mathbf{S}_j^t + J g_{t2} \sum_{\langle m,n \rangle} \mathbf{S}_m^t \cdot \mathbf{S}_n^t
+ J_{g1} g_{\delta 1} \sum_i \mathbf{S}_i^t \cdot \mathbf{S}_i^t,\]

where the operators \(c_{\sigma}\) and \(d_{\sigma}\) represent electron operators with spin \(\sigma\) for layers 1 and 2, respectively, \(\langle i,j \rangle\) and \(\langle m,n \rangle\) refer to nearest-neighbor and next-nearest-neighbor pairs (and we have implicitly assumed \(i < j\) and similarly for \(m\) and \(n\)), and \(\mathbf{S}_i^t\) and \(\mathbf{S}_i^d\) denote the spin-1/2 operators in each layer. In our model, the dopings of the two layers are independently tuned through the chemical potentials \(\mu_1\) and \(\mu_2\). At a general level, the two layers are coupled via the single-particle tunneling contribution \(t_{g1} g_{\delta 1}\) and through the exchange term \(J_{g1} g_{\delta 1}\), where \(g_{\delta 1} = \sqrt{g_{\delta 1}^t g_{\delta 1}^d}\) and \(g_{\delta 1} = \sqrt{g_{\delta 1}^t g_{\delta 1}^d}\).

In Appendix A, we briefly introduce the methodology and the numerical procedure in the context of the single layer following Zhang and Rice.\(^{47}\) The advantage of starting with this effective low-energy theory is that the d-wave superconducting ground state can be studied essentially using the usual (unprojected) BCS wave function. In the superconducting state, the results obtained within this method are in excellent agreement with variational Monte Carlo for projected d-wave states.\(^{48}\)

The main results for the single-layer situation are presented in Fig. 2. We check that the Fermi liquid order
On the other hand, as mentioned by Lee and Wen in 1997, the thermal excitation of quasiparticles near the nodal points rather produce a linear decrease of the superfluid stiffness $\rho_s(T)$ with temperature. This is the earliest experimental evidence of $d$-wave symmetry. Now, coming back to the Kosterlitz-Thouless scenario, this implies that the $\rho_s$ which controls the transition is not $\rho_s(0)$ but $\rho_s(T) \sim \rho_s(0) - g(T)$, where $g(T)$ is a linear function at low temperatures. Thus, $T_c$ can also be defined by $\rho_s(T_c) = 0$. Then, $T_c$ can also be evaluated numerically using Eq. (B1). Performing an expansion very close to the nodal points leads to:

$$g(T \to 0) = aT, \quad a = \alpha \frac{2\ln 2}{\pi} \frac{v_F}{\Delta}.$$  

(2)

and the ratio between the longitudinal and transverse velocities at the nodes reads (see Appendix B)

$$v_F/v_{\Delta} = \frac{2gt}{\Delta}.$$  

(3)

(We neglect the temperature dependence of $\chi$ and $\Delta$ below $T_c$ as $J \gg T$.) The ratio $v_F/v_{\Delta}$ is measured through the thermal conductivity. An important assumption made in Eq. (2) is that the $d$-wave quasiparticles are characterized by a renormalized current $-aev_F$ (see Appendix B). We introduce the parameter $\alpha$ which can be seen as a phenomenological Landau parameter inherited from the normal state. In principle, the quasiparticle charge $ae$ should be determined experimentally.

To have a good agreement between the two definitions of $T_c$ and to reproduce the dome-shaped $T_c(\delta)$ phase diagram of the single layer (see Fig. 2), then we fix $\alpha \sim 0.9$. Note that the value of $\alpha$ depends on the precise scheme used to treat interactions close to the Mott state.

III. BILAYER AT OPTIMAL DOPING

First, we apply the methodology of Sec. II to the optimally doped bilayer system. We intend to check that the superconducting state and therefore $T_c$ are rather stable toward single-(quasi)particle tunneling favored by the transverse hopping term $t_{\perp}$. In fact, since the transverse hopping term is still weakened by the Gutzwiller statistical weighting factor $g_{t,\perp}$ (which is equal to $g_t$ for symmetric layers), we shall show that $T_c$ is almost unchanged until moderate values of $t_{\perp}$ where $g_{t,\perp}f_{\perp} \sim J$. Essentially, the prominent superconducting gap in each layer tends to prevent the proliferation of quasiparticles.

A. Diagonalization in the band basis

In the case of a symmetric bilayer model (with equal hole dopings $\delta_1 = \delta_2 = \delta$ and $\mu_1 = \mu_2 = \mu$) it is convenient to use the bonding and antibonding representation:

$$b_{i\sigma} = \frac{1}{\sqrt{2}}(c_{i\sigma} + d_{i\sigma}), \quad a_{i\sigma} = \frac{1}{\sqrt{2}}(c_{i\sigma} - d_{i\sigma}),$$  

(4)

which allows to diagonalize all the single-particle hopping terms and therefore to treat $t_{\perp}$ nonperturbatively.
It is also judicious to introduce explicitly the mean-field order parameters for the two layers:

\[ \chi_{ij} = \frac{3}{4} g_{ij} \sum_{\sigma} \langle c_{i\sigma} c_{j\sigma} \rangle, \]

\[ \chi_{ij}^{\perp} = \frac{3}{4} g_{ij} \sum_{\sigma} \langle d_{i\sigma} d_{j\sigma} \rangle, \]

\[ \chi_{ii} = \frac{3}{4} g_{ii} \sum_{\sigma} \langle c_{i\sigma} c_{i\sigma} \rangle, \]  

\[ \Delta_{ij} = \frac{3}{4} g_{ij} \sum_{\sigma, \sigma'} \epsilon_{\sigma\sigma'} \langle c_{i\sigma} c_{j\sigma'} \rangle, \]  

\[ \Delta_{ij}^{\perp} = \frac{3}{4} g_{ij} \sum_{\sigma, \sigma'} \epsilon_{\sigma\sigma'} \langle d_{i\sigma} d_{j\sigma'} \rangle. \]  

(5)

For symmetric layers, we can define \( g_{ij} = g_{i\perp} = g_{i} = 4/(1 + \delta)^{2} \), and we look for mean-field solutions \( \chi_{ij} = \chi_{i}, \chi_{ij}^{\perp} = \chi_{i} \), where \( \chi_{1} = \chi_{2} = \chi, \chi_{i}^{\perp} = \chi_{\perp} \), \( \Delta_{ij} = \pm \Delta_{i} \) for two nearest neighbors along the \( x \) direction and \( -\Delta_{1} \) for two nearest neighbors along the \( y \) direction, and similarly for the second layer with \( \Delta_{1} = \Delta_{2} = \Delta \).

We also check that for \( 0 < t_{1}/t < 0.5 \), the order parameter \( \Delta_{ij}^{\perp} \) is always negligible which means that the only pairing contribution is the intralayer pure \( d \)-wave contribution. [In this paper, we are not interested in the regime of (very large) interlayer transverse hopping amplitudes.] Hereafter, we thus omit the negligible contribution from \( \Delta_{ij}^{\perp} \). Therefore the main coupling between the layers is the single-(quasi)particle tunneling term (when assuming \( J_{1} \ll t_{1}^{2}/U \) and the term \( J_{\perp} \) just renormalizes \( t_{\perp} \) by producing a finite \( \chi_{\perp} \).

In the band basis, the mean-field Hamiltonian reads

\[ H_{\text{sym}} = H_{\text{Kin}} + H_{\Delta} + H_{\text{const}}, \]  

(6)

where

\[ H_{\text{Kin}} = \sum_{k_0} \xi_{k,b} b_{k_0}^{\dagger} b_{k_0} + \sum_{k_0} \xi_{k,a} a_{k_0}^{\dagger} a_{k_0}, \]

\[ H_{\Delta} = \sum_{k} \Delta_{k,b} b_{k_1}^{\dagger} b_{-k_1} + \Delta_{k,a} a_{k_1}^{\dagger} a_{-k_1} + \text{H.c.}, \]  

(7)

\[ H_{\text{const}} = N_{s} \sum_{i=1,2,\perp} \left[ \frac{|\chi|^{2}}{2g_{i}} + \frac{J^{2} \epsilon_{\perp}^{2}}{4g_{i}} - 2N_{s} \mu \delta. \right] \]

Our convention for the chemical potential follows that of Ref. 47 and \( N_{s} \) is the total number of sites. We identify

\[ \xi_{k,b/a} = -(2g_{i} + \chi)(\cos(k_{x}) + \cos(k_{y})) \]

\[ -4g_{i} t_{\perp} \cos(k_{x}) \cos(k_{y}) \pm g_{i} t_{\perp} \pm \chi_{\perp} \right) - \mu. \]  

(8)

For simplicity, the lattice spacing is set to unity and for symmetric layers, \( g_{\perp} = \sqrt{3}g_{1}/2 = g_{1} = 2\delta/(1 + \delta) \). The Fermi surfaces associated with the two bands get split as a result of the transverse hopping amplitude \( t_{\perp} \) and \( \chi_{\perp} \). Further, the pairing parameters \( \Delta_{k,b} \) and \( \Delta_{k,a} \) are coupled through the mean-field order parameter \( \Delta \); more precisely, neglecting \( \Delta_{i}^{\perp} \) results in

\[ \Delta_{k,a} = \Delta_{k,b} = \Delta(\cos(k_{x}) - \cos(k_{y})). \]  

(9)

Interestingly, one can easily diagonalize \( H_{\text{sym}} \) for any value of \( t_{\perp} \) and the mean-field free energy is given by (again \( \chi_{1} = \chi_{2} = \chi, \Delta_{1} = \Delta_{2} = \Delta, \) and \( \Delta_{i} = 0)\):

\[ F_{\text{sym}}^{MF} = -2T \sum_{k, i=a,b} \ln \left[ \cosh \left( \frac{E_{k,i}}{2T} \right) \right] \]

\[ + N_{s} \sum_{i=1,2,\perp} \left[ \frac{|\chi|^{2}}{2g_{i}} + \frac{J^{2} \epsilon_{\perp}^{2}}{4g_{i}} \right] - 2N_{s} \mu \delta. \]  

(10)

The quasiparticle excitation energy for each band is reminiscent of the BCS theory:

\[ E_{k,a/b} = \sqrt{(\xi_{k,a/b})^{2} + (\Delta_{k,a/b})^{2}} \]  

(11)

The mean-field equations can be obtained by minimizing the free energy with respect to \( \mu, \chi, \Delta, \) and \( \chi_{\perp} \) along the lines of the single-layer case and at zero temperature:

\[ \delta = \frac{1}{2N_{s}} \sum_{i=a,b} \sum_{k} \tilde{\xi}_{k,i} E_{k,i}, \]

\[ \chi = \frac{3}{8N_{s}} g_{i} J_{1} \sum_{i,a,b} \sum_{k} (\cos(k_{x}) + \cos(k_{y})) \xi_{k,i}, \]

\[ \Delta = \frac{3}{8N_{s}} g_{i} J_{1} \sum_{a,b} \sum_{k} (\cos(k_{x}) - \cos(k_{y})) \Delta_{k,i}, \]

\[ \chi_{\perp} = \frac{3}{8N_{s}} g_{i} J_{\perp} \sum_{j,a,b} \sum_{k} \sqrt{\xi_{k,j}} \Delta_{k,j}, \]  

(12)

where in the last line \( j = + \) when \( j = a \) and \( j = - \) when \( j = b \). Results for the mean-field order parameters at zero temperature are shown in Fig. 3. Here, it is worth mentioning that even though \( \chi_{\perp} \) increases as a result of the finite \( t_{\perp} \) the \( d \)-wave gap remains almost constant reflecting the stability of

![FIG. 3. (Color online) Magnitudes of the order parameters (in units of \( 3g_{1}J/4 \)) and superfluid density (in units of \( t_{\perp} \)) for the optimally doped bilayer system at zero temperature as a function of \( t_{\perp}/t \). Optimal doping means \( \delta = 0.17 \), \( J/t = 0.2 \), and for this figure, \( t'/t = -0.3 \neq 0 \).](image-url)
the $d$-wave state toward the interlayer single-(quasi)particle tunneling term.

Further, it should be noted that in the band representation the two bands are still characterized by the same $d$-wave gap. However, details of their distinct Fermi surfaces may matter when evaluating the superfluid stiffness.

B. Superfluid density and $T_c$

The diamagnetic current is $(\mathcal{J}_D)_\mu = D_{\mu \nu} A_\nu$, where

$$D_{\mu \nu} = \sum_{k, \sigma} \frac{\partial^2 \xi_0^{k,\sigma}}{\partial k_\mu \partial k_\nu} (e_k^{a,\sigma} c_{k,\sigma} + d_k^{d,\sigma} d_{k,\sigma}),$$

(13)

and $\xi_0^{k,\sigma}$ is the “bare” spectrum (the magnetic term $J$ does not contribute to the electric current):

$$\xi_0^{k,\sigma} = -2tg_1(\cos(k_x) + \cos(k_y)) - 4g_1t' \cos(k_x) \cos(k_y).$$

The vector potential $A$ is directed along the layers. Then, we can rewrite $D_{\mu \nu}$ in the band basis as

$$D_{\mu \nu} = \sum_{k, \sigma} \frac{\partial^2 \xi_0^{k,\sigma}}{\partial k_\mu \partial k_\nu} (b_k^{a,\sigma} b_{k,\sigma} + a_k^{d,\sigma} a_{k,\sigma}).$$

(15)

Using the standard BCS ground-state wave function and the mean-field Hamiltonian in the band representation, then we identify

$$\sum_{\sigma} (b_k^{a,\sigma} b_{k,\sigma}) = 1 - \frac{\xi_{k,b}}{E_{k,b}} \tanh\left(\frac{E_{k,b}}{2T}\right),$$

(16)

We obtain $(a_k^{d,\sigma} a_{k,\sigma})$ in a similar way. The zero-temperature part of the superfluid density then takes the form

$$\rho_s(T = 0) = \frac{1}{N_s} \sum_{k,i=a,b} \xi_{k,0}'' \left(1 - \frac{\xi_{k,i}}{E_{k,i}}\right).$$

(17)

Here, $\xi_{k,0}'' = d^2 \xi_0^{k,\sigma}/dk_x^2$ means that the vector potential is directed along the $x$ axis. For small $t_\perp$, we find the following expression:

$$\rho_s(T = 0) \approx 1 + \frac{3}{2\rho_s(0)} \sum_k (t_\perp g_t + \chi_\perp) \frac{\xi_{k,0}''}{E_k^2},$$

(18)

with $\rho_s(0)$ being the zero-temperature superfluid density of the isolated layer and $\xi_{k}$ and $E_k$ of the isolated layer are defined in Appendix A. At a general level, $\sum_k \xi_{k,0}'' \xi_{k,0}/E_k^2 < 0$, which tends to suggest a light downturn of the zero-temperature superfluid density when switching on the interlayer coupling $t_\perp$. On the other hand, we check that the exact superfluid density at zero temperature computed from Eq. (B1) does not substantially decrease until quite large values of $t_\perp \sim 0.5t$. At small values of $t_\perp$, we note an excellent agreement between the exact expression of $\rho_s(T = 0)$ in Eq. (B1) and the weak-coupling approximation in Eq. (18); see Fig. 4.

To compute the critical temperature $T_c$ for the bilayer system at optimal doping, we follow Goren and Altman and diagonalize the mean-field Hamiltonian in the layer basis. The critical temperature $T_c$ is defined via Eq. (B1) by $\rho_s(T_c) = 0$ in the layer and band basis. Remember that the transition temperature $T_c$ can be equivalently defined in the band basis via Eq. (10).

FIG. 4. (Color online) $\rho_s(T = 0)$ from Eq. (B1) (in units of $t$) and a weak-coupling approximation in the band basis ($t' = 0$).

At low temperatures, the linear $T$ dependence of the superfluid stiffness essentially stems from the paramagnetic component (see Appendix B). In the band basis, interestingly, this can be separated into bonding and antibonding contributions. Close to the nodal points, we get

$$\rho_s(T) \approx \rho_s(T = 0) - \sum_{i=a,b} \alpha_i^2 \frac{2\ln 2}{\pi} \frac{T}{\Delta_{i}},$$

(19)

where formally

$$\alpha_i = \frac{v_F}{v_{F,i}},$$

(20)

and $v_F$ for the single layer has been defined in Appendix B. It is relevant to mention that in the band basis close to the nodal points the longitudinal and transverse velocities obey

$$\frac{v_{F,a}}{v_{\Delta,a}} = \frac{v_{F,b}}{v_{\Delta,b}} = \frac{2g_1 t + \chi}{\Delta}.$$

(21)

This shows that the ratio $(v_{F,a,b}/v_{\Delta,a,b})$ remains quite constant until moderate values of $t_\perp$; in particular, it does not involve $\chi_\perp$. This allows us to safely approximate $\alpha_i \sim \alpha \sim 0.9$. We shall also mention that since the ratio $v_{F,i}/\Delta_{i}$ remains almost identical to that of the isolated layer until moderate values of $t_\perp$ this already suggests a very slow reduction of $T_c$ with $t_\perp$.

For small values of $t_\perp$, the zero-temperature value of the gap obeys

$$\frac{\Delta(t_\perp)}{\Delta} = 1 - \sum_k \frac{(t_\perp g_t + \chi_\perp)^2}{4E_k^2} [\cos(k_x) - \cos(k_y)]^2$$

(22)

(where $\Delta$ corresponds to the value of the gap for the isolated layer at optimal doping; see Fig. 2). For small $t_\perp$, we predict $T_c = T_c^0 - C(t_\perp + \chi_\perp)^2$ with $C > 0$.

The curve of $T_c$ versus $t_\perp$ for the optimally doped bilayer system is presented in Fig. 5. This unambiguously confirms that the bilayer system at optimal doping is rather stable toward single-(quasi)particle tunneling until quite large values of $t_\perp$, defined roughly by $g_t t_\perp \sim J$ ($J$ controls the pairing properties of the two layers). The prominent superconducting gap hinders the proliferation of quasiparticles close to the nodal points.
We use the parameters corresponding to the two approaches defined in Sec. III for accessing $T_c$ doped layers, i.e., enhancing quasiparticle nodal contribution for weak asymmetries, then the bonding and antibonding bands which helps diminish the finite hole asymmetry will result in a pairing term coupling in a decrease of the hole dopings of the layers will result in an increase or roughen the hole density in each layer at optimal doping.

We seek to understand whether such a finite asymmetry in the optimally doped situation. The results which also results in

$$\Delta_{k}^{as} = \frac{1}{2}(\Delta_1 - \Delta_2)[\cos(k_x) - \cos(k_y)].$$

Concerning the $H_{sym}$ part this involves $\xi_{k}^{av}$ and $\Delta_{k}^{av}$:

$$\xi_{k, b/a} = -\frac{1}{2}(\mu_2 + \mu_2) + g_{1}l_{1} + \chi_1 - \frac{1}{2}(g_{1} + g_{2}) + \frac{1}{2}(\chi_1 + \chi_2) [\cos(k_x) + \cos(k_y)]$$

$$\Delta_{k, a} = \Delta_{k, b} = \frac{1}{2}(\Delta_1 + \Delta_2)[\cos(k_x) - \cos(k_y)].$$

One can still compute the critical temperature $T_c$ and the superfluid density $\rho_s(T_c)$ [from Eq. (B1)] in the layer basis by diagonalizing the Hamiltonian. On the other hand, to gain some intuition, we also treat the asymmetry terms in the Hamiltonian to second order in perturbation theory (which is justified for quite small asymmetries around the optimal doping).

Essentially, in the band basis, this results in corrections to $\xi_{k, a/b}$ and $\Delta_{k, a/b}$ such that $\xi_{k, b}$ and $\Delta_{k, b}$ become $\tilde{\xi}_{k, b}$ and $\tilde{\Delta}_{k, b}$ defined as (see Appendix C)

$$\xi_{k, b} = \frac{1}{E_{k, a}}[(\xi_{k}^{av})^2 \xi_{k, a} - (\Delta_{k}^{av})^2 \xi_{k, a}] + 2\xi_{k}^{av}\Delta_{k}^{av}\Delta_{k, a},$$

$$\Delta_{k, b} = \frac{1}{E_{k, a}}[(\Delta_{k}^{av})^2 \Delta_{k, a} - (\xi_{k}^{av})^2 \Delta_{k, a}] + 2\xi_{k}^{av}\Delta_{k}^{av}\Delta_{k, a}. $$

and similarly for $\tilde{\xi}_{k, a}$ and $\tilde{\Delta}_{k, a}$. (There is no first-order correction to the ground-state energy.) Note that even though the main pairing contribution is the pure $d$-wave intraband component, the interband pairing correlations favored by $\Delta_{k}^{as}$ will contribute to reduce the nodal quasiparticle contribution to the superfluid stiffness $\rho_s(T_c)$.

From second-order perturbation theory, the effect of $\tilde{\xi}_{k}^{av}$ and $\tilde{\Delta}_{k}^{av}$ is primarily to renormalize the band structure parameters entering into the energies $E_{k, a}$ and $E_{k, b}$ of the quasiparticles at the nodal points.

**B. Renormalization of nodal contributions**

The next step to compute the transition temperature $T_c$ is to check how $\xi_{k, a/b}$ and $\Delta_{k, a/b}$ vary to linear order in $k$ space for points around the nodal points.

Notice that the bonding (b) Fermi “surface” is larger than the antibonding (a) Fermi surface. This is a very general fact stemming from the finite interlayer hopping term $t_1$. Therefore, we can denote $N_b$ and $N_a$ the nodes associated with the bonding and antibonding bands, respectively, and $k_{ab} > 0$ (proportional to $t_1$) is the $k$ space distance between the bonding and antibonding Fermi surfaces. Now, $(k_1, k_2)$ are local coordinates with origin at $N_b$ such that

$$\xi_{k, b} = v_{F,b} k_1,$$ $$\Delta_{k, b} = v_{\Delta,b} k_2,$$ $$\xi_{k, a} = v_{F,a} (k_1 + k_{ab}),$$ $$\Delta_{k, a} = v_{\Delta,a} k_2, $$

where $k_1, k_2 \to 0$. Then, terms such as $(\Delta_{k}^{av})^2$ are of order $k_2^2$ and therefore do not contribute to linear order. As a result, we

\[024526-6\]
can approximate
\[ \tilde{\xi}_{k,b} \approx \xi_{k,b} \left( 1 - \frac{k_1}{k_{ab}} \right) - \frac{\left( \tilde{\xi}_{N_b}^{\alpha} \right)^2}{E_{k,a}^2} \] (31)

The first correction term in \( \tilde{\xi}_{k,b} \) shifts the position of the node \( N_B \) and the second term gives a correction to \( v_{F,b} \):
\[ \tilde{v}_{F,b} = v_{F,b} + \frac{\left( \tilde{\xi}_{N_b}^{\alpha} \right)^2}{v_{F,a}k_{ab}}. \] (32)

Writing \( \Delta_{\alpha}^{ab} = v_{\Delta}^{ab} k_2 \) we also get
\[ \tilde{\Delta}_{k,b} \approx \Delta_{k,b} \left( 1 - \frac{k_1}{k_{ab}} \right) - \frac{2v_{\Delta}^{ab} v_{F,a} k_{ab} v_{\Delta}^{ab} - \left( \tilde{\xi}_{N_b}^{\alpha} \right)^2}{v_{\Delta,a}(k_{ab})^2}. \] (33)

Therefore, \( v_{\Delta,b} \) is renormalized as
\[ v_{\Delta,b} = 1 \left( \frac{v_{F,a}k_{ab}}{v_{F,b}(k_{ab})} \right) \left[ 2v_{\Delta}^{ab} v_{F,a} k_{ab} v_{\Delta}^{ab} - \left( \tilde{\xi}_{N_b}^{\alpha} \right)^2 \right] v_{\Delta,a}. \] (34)

Similarly, we also find
\[ \tilde{v}_{F,a} = v_{F,a} + \frac{\left( \tilde{\xi}_{N_b}^{\alpha} \right)^2}{v_{F,b}k_{ab}}. \] (35)

and
\[ \tilde{v}_{\Delta,a} = v_{\Delta,a} + \frac{1}{(v_{F,a}k_{ab})^2} \left[ 2v_{\Delta}^{ab} v_{F,a} k_{ab} v_{\Delta}^{ab} + \left( \tilde{\xi}_{N_b}^{\alpha} \right)^2 \right] v_{\Delta,b}. \] (36)

Now, a close inspection of all the contributions leads to
\[ \frac{\tilde{v}_{F,a}}{v_{\Delta,a}} + \frac{\tilde{v}_{F,b}}{v_{\Delta,b}} \approx \frac{v_{F,a}v_{\Delta,a}}{v_{\Delta,a}v_{F,b}k_{ab}} \left( 1 - \frac{2v_{\Delta}^{ab} v_{F,a} k_{ab} v_{\Delta}^{ab}}{v_{F,a}v_{F,b}k_{ab}} \right) \] (37)
\[ + \frac{v_{F,b}v_{\Delta,b}}{v_{\Delta,b}v_{F,a}k_{ab}} \left( 1 + \frac{2v_{\Delta}^{ab} v_{F,a} k_{ab} v_{\Delta}^{ab}}{v_{F,a}v_{F,b}k_{ab}} \right). \]

It should be noted that for very small values of \( t_\perp \) such that \( k_{ab} \to 0 \) then we could approximate \( \tilde{\xi}_{N_b}^{\alpha} \approx \tilde{\xi}_{N_b}^{\alpha} \) and the nodal corrections would have practically no effect. For the symmetric case, remember that \( v_{F,a}/v_{\Delta,a} = v_{F,b}/v_{\Delta,b} \) and we also check that \( v_{\Delta,a}v_{F,b} = v_{\Delta,b}v_{F,a} \).

C. Enhancement of \( T_c \)

Now, let us assume a moderate value of \( t_\perp \) such that \( 0 \ll g_{1,2} t_\perp \ll J \). At a general level, we can compute \( \tilde{\xi}_{N_b}^{\alpha} \) and \( \tilde{\xi}_{N_b}^{\alpha} \) numerically and then extract the superconducting transition \( T_c \). Here, it should be noted that since a prominent \( t_\perp \) makes \( \cos(k_x) + \cos(k_y) \) larger for a small Fermi surface and \( (g_{1,2} \ll g_{1,2}) < 0 \) then this immediately implies \( \tilde{\xi}_{N_b}^{\alpha} > \tilde{\xi}_{N_b}^{\alpha} \) (for \( \mu_1 \sim \mu_2 \) and \( \chi_1 \sim \chi_2 \)). Based on the nodal quasiparticle contribution only, in the case of a finite (small) hole asymmetry, one then predicts
\[ \frac{T_c}{T_{c,\text{opt}}} \approx \left( 1 + \frac{\tilde{\xi}_{N_b}^{\alpha} v_{\Delta}^{ab} v_{F,a} k_{ab}}{v_{\Delta,a}v_{F,b}k_{ab}} \right)^{-1} > 1. \] (38)

FIG. 6. Here, we consider that the overdoped layer is sufficiently doped such that it is described by a free-electron model (\( \alpha_2 = 1 \) and \( \chi_2 = 0 \) (Ref. 49); the doping level of the metallic layer is \( \delta_1 = 0.35 \). Parameters are \( t_\perp/t = 0.5 \), \( J/t = 0.3 \), and similar to Ref. 49; for this figure, we set the renormalized quasiparticle charge of \( \alpha_1 = 0.5 \) and \( \delta_1 = \delta_2 \). Here, \( T_{c,\text{opt}}^\text{Max} \) refers to the maximal value of \( T_c \) for the single layer. The enhancement of \( T_c \) is in agreement with Ref. 49 (but it clearly depends on the precise choice of \( \alpha_1 \)).

Here, \( T_{c,\text{opt}} \) refers to \( T_c \) at optimal doping for the symmetric bilayer. In Fig. 1, we compare the result of Eq. (38) valid for a small doping asymmetry with the numerical results obtained in the layer basis directly. Both results seem in excellent agreement for small asymmetries. This traduces that additional (weak) superconducting fluctuations mediated by \( \Delta_{\alpha}^{ab} \) mostly affect the nodal contribution(s) whereas other regions (in \( k \) space) are protected by the large \( d \)-wave gap.

The enhancement of \( T_c \) is attributed to the interplay between interband pairing correlations (\( v_{\Delta}^{ab} \)) and the finite interlayer hopping. This result relies on the existence of a large and small Fermi surface induced by a finite interlayer hopping term. In Fig. 1 we maintain the average hole density \( (\delta_1 + \delta_2)/2 \sim 0.2 \) fixed and each layer exhibits intrinsic \( d \)-wave pairing correlations (the parameter \( \alpha \sim 0.9 \) for each layer). In Fig. 6, in contrast, we consider an overdoped layer described by a free-electron-like model (with \( \chi_2 = 1 \) and essentially we corroborate the result obtained in Ref. 49, choosing \( \alpha_1 = 0.5 \) for the underdoped layer. Hence, we conclude that two scenarios allow one to increase \( T_c \) in bilayer systems; one relies on the presence of a very overdoped free-electron layer and the other relies on the enhancement of pairing fluctuations in the band basis induced by a finite hole asymmetry around optimal doping.

V. CONCLUSION

In this paper we corroborate that significant enhancement of \( T_c \) in strongly correlated heterostructures is possible under realistic conditions. More precisely, applying an effective low-energy theory of the doped Mott insulator we have investigated a bilayer Hubbard system where both layers exhibit intrinsic intralayer (intraband) \( d \)-wave superconducting correlations. Using the renormalized mean-field theory which is usually well controlled when focusing primarily on the
superconducting state, we have shown that the increase of $T_c$ results from the delicate balance between the moderate single-particle tunneling term coupling the layers and the finite hole asymmetry around optimal doping which tends to reduce the quasiparticle contribution to the superfluid stiffness by reinforcing superconducting fluctuations. In fact, we have built the BCS Hamiltonian in the band representation of the bilayer system, which is particularly judicious for building a nonperturbative theory in the single-particle tunneling term coupling the layers. We have also shown that the $d$-wave superconducting state is quite robust toward the interlayer single-(quasi)particle tunneling term. The key point to enhance $T_c$ in these heterostructures is that a finite interlayer hopping produces a larger and smaller Fermi surface and a moderate superconductivity (see Fig. 5).

It is important to distinguish this scenario based on two layers exhibiting prominent $d$-wave superconducting fluctuations. This scenario requires that both bands are filled ($v_F,a \neq 0$ and $v_F,b \neq 0$) and hence $t_{\perp}$ should not be too large; a too large $t_{\perp}$ rather favors single-quasiparticle interlayer tunneling and therefore is generally not helpful for superconductivity (see Fig. 5).

It should also be mentioned that in this paper we have ignored gauge (phase) fluctuation effects which may play an important role for (quasi-) two-dimensional systems.

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**APPENDIX A: DOPED MOTT INSULATOR AND $d$-WAVE SUPERCONDUCTIVITY**

The effective Hamiltonian of a doped Mott insulator takes the form

$$H_{t'\gamma, J} = -t g_t \sum_{\langle i,j \rangle \sigma} c_{i \sigma}^\dagger c_{j \sigma} + \text{H.c.}$$

$$-t' g_t \sum_{\langle m,n \rangle \sigma} c_{m \sigma}^\dagger c_{n \sigma} + \text{H.c.}$$

$$-\mu \sum_{\sigma} c_{i \sigma}^\dagger c_{i \sigma} + J g_t \sum_{\langle i,j \rangle} S_i^z S_j^z.$$  (A1)

Here, $\langle i,j \rangle$ represent the nearest-neighbor pairs and $\langle m,n \rangle$ the next-nearest-neighbor pairs (and we implicitly assume that $i < j$ and similarly for $m$ and $n$). The statistical weighting factors for the hopping and spin exchange coupling are $g_t = \frac{2t_t}{1+t_t}$ (Ref. 64) and $g_s = \frac{4}{1+4\mu}$ (Ref. 47), respectively, and $\delta$ is the hole doping. Below, we closely follow the notations of Zhang and Rice.47

We then introduce the mean-field order parameters:

$$\chi_{ij} = \frac{3}{4} g_t J \sum_{\sigma} c_{i \sigma}^\dagger c_{j \sigma}$$

$$\Delta_{ij} = \frac{3}{4} g_t J \sum_{\sigma \sigma'} \epsilon_{\sigma \sigma'} c_{i \sigma} c_{j \sigma'},$$  (A2)

with $\epsilon_{1,1} = 1 = -\epsilon_{1,-1}$ and zero otherwise. Then, we look for mean-field solutions with $\chi_{ij} = \chi$, and $\Delta_{ij} = \Delta$ along the $x$ direction and $\Delta_{ij} = -\Delta$ along the $y$ direction to ensure $d$-wave pairing. The mean-field Hamiltonian then reads

$$H_{t'\gamma, J}^{MF} = H_{\text{Kin}} + H_{\Delta} + H_{\text{const}},$$

$$H_{\text{Kin}} = \sum_{k \sigma} \epsilon_k c_{k \sigma}^\dagger c_{k \sigma}$$

$$H_{\Delta} = \frac{\Delta}{2} \sum_{k} (c_{k \uparrow}^\dagger c_{-k \downarrow}^\dagger - c_{-k \downarrow}^\dagger c_{k \uparrow}^\dagger) + \text{H.c.},$$  (A3)

$$H_{\text{const}} = N_s \left[ \frac{|\chi|^2}{2 g_t J} + \frac{|\Delta|^2}{2 g_t J} \right] - N_s \mu \delta,$$

where $N_s$ is the total number of sites (and the chemical potential has been introduced following Zhang and Rice47). Assuming a square lattice geometry, we identify

$$\xi_k = -(2t g_t + \chi)[\cos(k_x) + \cos(k_y)]$$

$$-4 g_t t' \cos(k_x) \cos(k_y) - \mu,$$  (A4)

$$\Delta_k = \Delta [\cos(k_x) - \cos(k_y)].$$

The mean-field free energy is given by

$$F_{MF} = -2T \sum_k \ln \left[ \cosh \left( \frac{E_k}{2T} \right) \right]$$

$$+ N_s \left[ \frac{|\chi|^2}{2 g_t J} + \frac{|\Delta|^2}{2 g_t J} \right] - N_s \mu \delta, $$  (A5)

where the quasiparticle excitation energy obeys

$$E_k = \sqrt{\xi_k^2 + \Delta_k^2}.$$  (A6)

The Boltzmann constant is set to unity. The mean-field equations can be obtained by directly minimizing the free energy with respect to $\chi$, $\Delta$ and by imposing $(\delta F_{MF}/\delta \mu) = 0$. The mean-field variables of Fig. 2 are solutions of the following equations:

$$\delta = \frac{1}{N_s} \sum_k \frac{\xi_k}{E_k} \tanh \left( \frac{E_k}{2T} \right),$$

$$\chi = -\frac{3}{4 N_s} g_t J \sum_k [\cos(k_x) + \cos(k_y)] \frac{\xi_k}{E_k} \tanh \left( \frac{E_k}{2T} \right),$$

$$\Delta = \frac{3}{4 N_s} g_t J \sum_k [\cos(k_x) - \cos(k_y)] \frac{\Delta_k}{E_k} \tanh \left( \frac{E_k}{2T} \right). $$  (A7)
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APPENDIX B: SUPERFLUID DENSITY AND $T_c$

The superfluid density is formally defined as

$$\rho_s^{\nu\nu} = \frac{1}{\text{Vol}} \left[ \frac{\partial^2 F_{MF}}{\partial A^\nu_\nu \partial A^\nu_\nu} \right]_{A=0}, \quad (B1)$$

where Vol is the volume of the system and $A$ is the vector potential entering in the kinetic part of the Hamiltonian through a phase

$$H_{\text{Kin}}(A) = -ig_t \sum_{(i,j)\sigma} e^{iA_{ij}} c^\dagger_{i\sigma} c_{j\sigma} - \frac{1}{2} g_t^0 \sum_{(m,n)\sigma} e^{iA_{mn}} c^\dagger_{m\sigma} c_{n\sigma}. \quad (B2)$$

Here, without loss of generality, we assume the vector potential to be along the $x$ axis: $A = A_x$. The superfluid density at any temperature can therefore be evaluated numerically through Eq. (B1).

Further, at $T = 0$, the superfluid density can be easily obtained analytically, and it is given by (see Sec. III B)

$$\rho_s(0) = \frac{1}{N_s} \sum_k \xi^2_k \left( 1 - \frac{\xi_k}{E_k} \right), \quad (B3)$$

where $\xi^2_k = d^2 \xi_k^0 / dk^2$ with $\xi_k^0 = -2tg_t[\cos(k_x) + \cos(k_y)] - 4g_t^0 t' \cos(k_x) \cos(k_y)$ being the hopping part of the kinetic energy. [Below, we neglect the $T$ dependence of this diamagnetic contribution since a power-counting argument shows that this $T$ dependence is $O(T^2)$.]  

At finite temperature, the superfluid density is inevitably suppressed by the normal state quasiparticle excitations near the four nodal points $q = (\pm q, \pm q)$ with $q = \pi / 2$ at half-filling. In the vicinity of the node ($q, q$), we have the anisotropic Dirac spectrum:

$$E_k \approx \sqrt{v_F^2 k_1^2 + v^2_{\Delta} k^2_2}, \quad (B4)$$

where for the square lattice

$$v_F = \sqrt{2} (2tg_t + \chi) \sin(q),$$

$$v_{\Delta} = \sqrt{2} \Delta \sin(q),$$

$$\cos(q) = -\frac{\mu}{2(2tg_t + \chi)}. \quad (B5)$$

$v_F$ and $v_{\Delta}$ are the nodal quasiparticle velocities in the longitudinal and transverse directions, respectively. For simplicity, here we assume that $t' = 0$ allowing a simple analytical solution. More precisely, by definition

$$v_{\Delta} = \left. \frac{\partial E_k}{\partial k_2} \right|_{k_1, k_2 \to 0}, \quad v_F = \left. \frac{\partial E_k}{\partial k_1} \right|_{k_1, k_2 \to 0}. \quad (B6)$$

where $k_1 = (k_x + k_y - 2q) / \sqrt{2}$ and $k_2 = (k_x - k_y) / \sqrt{2}$ with $q$ being associated with the Fermi momentum $k_F = (q, q)$ on the nodal point ($q = \pi / 2$ at half-filling on the square lattice if $t' = 0$). The Fermi momentum obeys

$$\xi_k \approx \sqrt{2} (2tg_t + \chi) \sin(q) k_1, \quad \Delta_k \approx -\sqrt{2} \Delta \sin(q) k_2. \quad (B8)$$

Therefore, we get $\cos(q) = -\frac{\mu}{2(2tg_t + \chi)}$. We can expand $\xi_k$ and $\Delta_k$ near a given node,

$$\xi_k \approx \sqrt{2} (2tg_t + \chi) \sin(q) k_1, \quad \Delta_k \approx -\sqrt{2} \Delta \sin(q) k_2. \quad (B8)$$

This results in Eqs. (B4) and (B5).

In the presence of a vector potential, the quasiparticle spectrum exhibits a shift:

$$E(k, A) = E(k) - j(k) \cdot A, \quad (B9)$$

where the current $j$ carried by the normal-state quasiparticles can be formally written as

$$j = -eav_F. \quad (B10)$$

Ignoring interactions between the quasiparticles would result in $\alpha = g_t v_F^2 / v_F$ where $v_F^2$ corresponds to the bare Fermi velocity when setting $\chi = 0$. Such a choice of $\alpha$ would not allow one to reproduce the dome-shaped $T_c(\delta)$. Therefore, in this paper, $\alpha \sim 0.9$ will be rather taken as an effective (constant, doping independent) parameter which can also be regarded as an effective charge. In Eq. (B1), we adjust the vector potential $A$ such that it reproduces the correct effective charge.

Using Eqs. (A5), (B1), (B4), and (B9) and performing the integral in Eq. (A5) in momentum space near the nodes gives the low-temperature linear approximation:

$$\rho_s(T) = \rho_s(0) - aT, \quad a = \frac{2 \ln 2}{\pi} \frac{v_F}{v_{\Delta}}. \quad (B11)$$

The ratio $v_{\Delta} / v_F$ near a nodal point reads

$$\frac{v_F}{v_{\Delta}} = \frac{2tg_t + \chi}{\Delta}. \quad (B12)$$

The transition temperature $T_c$ is determined through Eq. (B1) as the temperature at which the superfluid density vanishes due to the thermal excitation of quasiparticles (but, not necessarily nodal); see Fig. 7.

Setting $\alpha \sim 0.9$ in Eq. (B1) through the vector potential $A$ allows us to recover a form of $T_c(\delta)$ which is reminiscent of

FIG. 7. (Color online) $\rho_s(T)$ in units of $\mu$ using Eq. (B1). The analytical approximation (B11) corresponds to a low-temperature expansion very close to the nodes. The parameters are the same as in Fig. 2 and $\alpha$ is fixed around $0.9$. Here, $\delta = 0.17$. 

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the superconducting order parameter
\[ \Delta_{SC}^2 = \langle \text{BCS} | \{ c_{i}^\dagger c_{j}^\dagger c_{i+l} c_{j+l} \} | \text{BCS} \rangle \sim g_{l}^2 \Delta_{0}^2 \] (B13)
for a large distance \( l \), as shown in Fig. 2.

**APPENDIX C: PERTURBATION THEORY**

Here, we derive Eqs. (29) in the main text obtained by treating \( H_{asy} \) in perturbation theory. First, it is convenient to write the Hamiltonians of each band as \( 2 \times 2 \) block matrices. When \( H_{asy} = 0 \) then this results in
\[
H_B = \begin{bmatrix} \xi_b & \Delta_b \\ \Delta_b & -\xi_b \end{bmatrix}, \quad H_A = \begin{bmatrix} \xi_a & \Delta_a \\ \Delta_a & -\xi_a \end{bmatrix}.
\] (C1)
For simplicity, we suppress the momentum index \( k \). The mixing between the bonding and antibonding sectors is given by \( V_{AB} = V_{BA} = H_{asy} \):
\[
H_{asy} = \begin{bmatrix} \xi_{as} & \Delta_{as} \\ \Delta_{as} & -\xi_{as} \end{bmatrix}.
\] (C2)
Solving the time-independent Schrödinger equation and integrating out the A subsystem the effective Hamiltonian for B subsystem is given by
\[
\tilde{H}_B = H_B + V_{BA}(H_A)^{-1}V_{AB},
\] (C3)
with \( V_{BA}(H_A)^{-1}V_{AB} = \frac{1}{E_a^2} \begin{bmatrix} \xi_{as} & \Delta_{as} \\ \Delta_{as} & -\xi_{as} \end{bmatrix} \begin{bmatrix} -\Delta_a & \xi_a \\ -\xi_a & \Delta_a \end{bmatrix} \begin{bmatrix} \xi_{as} & \Delta_{as} \\ \Delta_{as} & -\xi_{as} \end{bmatrix} \begin{bmatrix} \xi_{as} & \Delta_{as} \\ \Delta_{as} & -\xi_{as} \end{bmatrix} \]
\] (C4)
Therefore, we check that
\[
H_B + V_{BA}(H_A)^{-1}V_{AB} = \begin{bmatrix} \tilde{\xi}_b & \tilde{\Delta}_b \\ \tilde{\Delta}_b & -\tilde{\xi}_b \end{bmatrix},
\] (C5)
where \( \tilde{\xi}_b \) and \( \tilde{\Delta}_b \) are precisely defined as
\[
\tilde{\xi}_b = \xi_b - \frac{1}{E_a^2} \left( (\xi_{as}^2)\xi_a - (\Delta_{as}^2)\xi_a + 2\xi_{as}\Delta_{as}\Delta_a \right),
\] (C6)
\[
\tilde{\Delta}_b = \Delta_b - \frac{1}{E_a^2} \left( (\Delta_{as}^2)\Delta_a - (\xi_{as}^2)\Delta_a + 2\xi_{as}\Delta_{as}\xi_a \right).
\]

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23. For a review, see D. Scalapino, e-print arXiv:cond-mat/9908287.